## FAIRCHILD

SEMICONDUCTOR®

## FDP8442\_F085

## N-Channel PowerTrench<sup>®</sup> MOSFET

## **40V, 80A, 3.1m**Ω

### Features

- Typ  $r_{DS(on)} = 2.3m\Omega$  at  $V_{GS} = 10V$ ,  $I_D = 80A$
- Typ Q<sub>g(10)</sub> = 181nC at V<sub>GS</sub> = 10V
- Low Miller Charge
- Low Q<sub>rr</sub> Body Diode
- UIS Capability (Single Pulse and Repetitive Pulse)
- Qualified to AEC Q101
- RoHS Compliant

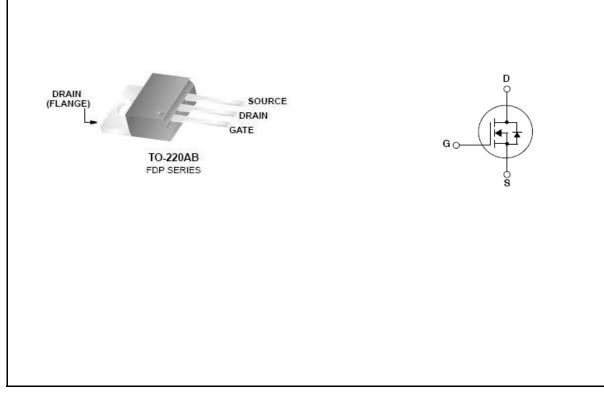


### May 2010

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### Applications

- Automotive Engine Control
- Powertrain Management
- Solenoid and Motor Drivers
- Electronic Steering
- Integrated Starter / Alternator
- Distributed Power Architectures and VRMs
- Primary Switch for 12V Systems



Symbol	Parameter					Ratings			Units			
V <sub>DSS</sub>	Drain to S	Drain to Source Voltage						40			V	
V <sub>GS</sub>	Gate to Source Voltage						±20			V		
	Drain Current Continuous (T <sub>C</sub> <158°C, V <sub>GS</sub> = 10V)					80						
I <sub>D</sub>	Drain Current Continuous ( $T_{amb} = 25^{\circ}C$ , $V_{GS} = 10V$ , with $R_{\theta,JA} = 62^{\circ}C/W$ )					23			Α			
	Pulsed						See Figure 4					
E <sub>AS</sub>	Single Pulse Avalanche Energy			(Note 1)			720			mJ		
PD	Power Dissipation					254			W/ºC			
	Derate above 25°C								1.7			
T <sub>J</sub> , T <sub>STG</sub>	Operating	and Storage Temp	erature						-55 to +1	75	°C	
Therm	al Cha	racteristics										
$R_{\theta JC}$	Thermal Resistance Junction to Case						0.59			°C/W		
$R_{\theta,JA}$	Thermal R	esistance Junction	to Ambient			(Not	te 2)	62			°C/W	
	ge Mar	king and Ore	dering Ir	nfor	mation							
Device	Marking	Device	Packag	e	Reel Si	ize	Tar	e Widt	'n	Quan	titv	
	P8442	FDP8442 F085	TO-220A		Tube	-	144	N/A		50 ur		
Electri	cal Cha	aracteristics	T <sub>J</sub> = 25°C u	Inless	otherwise n	oted						
Symbol		Parameter			Test Cond	ditions		Min	Тур	Max	Units	
Off Cha	racterist	ics										
B <sub>VDSS</sub>	Drain to S	Drain to Source Breakdown Voltage		$I_{D} = 250 \mu A, V_{GS} = 0 V$				40	-	-	V	
I <sub>DSS</sub>	Zero Gate Voltage Drain Current		ent	$V_{DS} = 32V$ $V_{GS} = 0V$ $T_J = 150^{\circ}C$			2 <sup>°</sup>	-	-	1 250	μA	
I <sub>GSS</sub>	Gate to Source Leakage Current		ent	$V_{GS} = \pm 20V$			-	-	-	±100	nA	
	racterist			00								
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage			$V_{DS} = V_{GS}, I_{D} = 250 \mu A$				2	2.9	4	V	
( )				I <sub>D</sub> = 80A, V <sub>GS</sub> = 10V				-	2.3	3.1		
r <sub>DS(on)</sub>	Drain to Source On Resistance		e	I <sub>D</sub> = 80A, V <sub>GS</sub> = 10V, T <sub>J</sub> = 175°C				-	3.9	5.3	mΩ	
Dynami	c Chara	cteristics										
C <sub>iss</sub>	Input Capacitance							-	12200	-	pF	
C <sub>oss</sub>	Output Capacitance Reverse Transfer Capacitance			$V_{DS} = 25V, V_{GS} = 0V,$ f = 1MHz				-	1040	-	pF	
C <sub>rss</sub>			e					-	640	-	pF	
R <sub>G</sub>	Gate Resistance			V <sub>GS</sub> = 0.5V, f = 1MHz				-	1.0	-	Ω	
Q <sub>g(TOT)</sub>	Total Gate Charge at 10V			V <sub>GS</sub> = 0 to 10V				-	181	235	nC	
Q <sub>g(TH)</sub>	Threshold	Gate Charge		V <sub>GS</sub> =	= 0 to 2V	$V_{DD} = 20$	v	-	23	30	nC	
Q <sub>gs</sub>	Gate to Source Gate Charge			I <sub>D</sub> = 80A				-	49	-	nC	
Q <sub>gs2</sub>	Gate Char	ge Threshold to Pla	teau	l <sub>g</sub> = 1mA			-	26	-	nC		
-	Gate to Dr			1			1 -		41		nC	

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Switchi	ng Characteristics					
t <sub>(on)</sub>	Turn-On Time		-	-	62	ns
t <sub>d(on)</sub>	Turn-On Delay Time		-	19.5	-	ns
t <sub>r</sub>	Turn-On Rise Time	V <sub>DD</sub> = 20V, I <sub>D</sub> = 80A	-	19.3	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time	$V_{DD} = 20V, I_D = 80A$ $V_{GS} = 10V, R_{GS} = 2Ω$	-	57	-	ns
t <sub>f</sub>	Turn-Off Fall Time		-	17.2	-	ns
t <sub>off</sub>	Turn-Off Time		-	-	118	ns
Drain-S	ource Diode Characteristics			1	T	I
V <sub>SD</sub>	Source to Drain Diode Voltage	I <sub>SD</sub> = 80A	-	0.9	1.25	V
	Source to Drain Diode Voltage	I <sub>SD</sub> = 40A	-	0.8	1.0	V
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> = 75A, di/dt = 100A/μs	-	49	64	ns

 $I_F = 75A$ , di/dt = 100A/ $\mu$ s

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70

91

nC

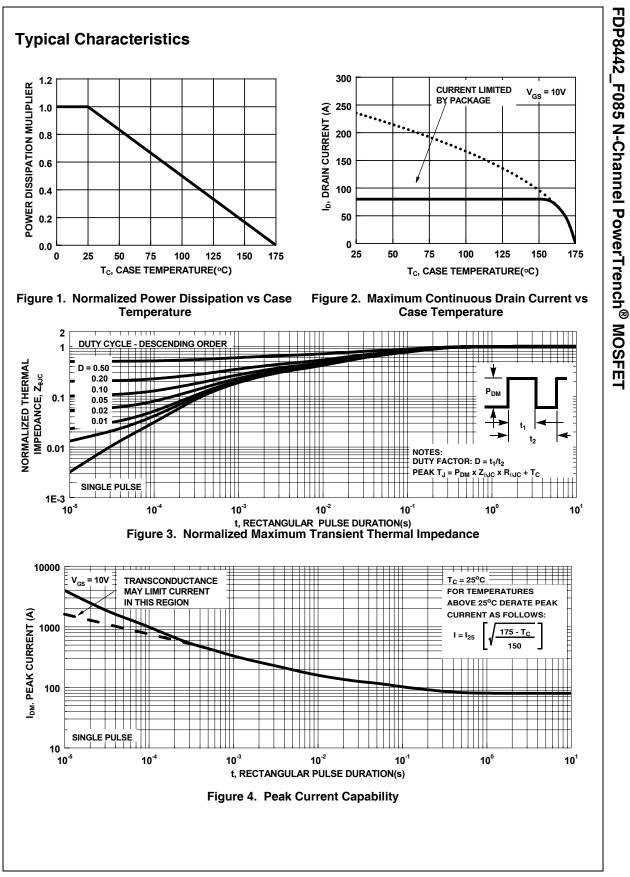
This product has been designed to meet the extreme test conditions and environment demanded by the automotive industry. For a copy of the requirements, see AEC Q101 at: http://www.aecouncil.com/ All Fairchild Semiconductor products are manufactured, assembled and tested under ISO9000 and QS9000 quality systems certification.

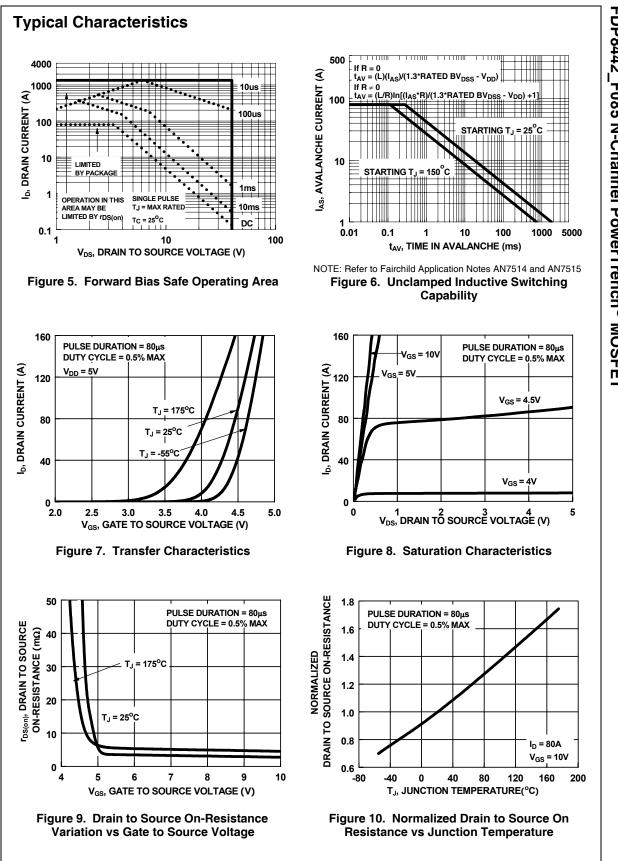
Qrr

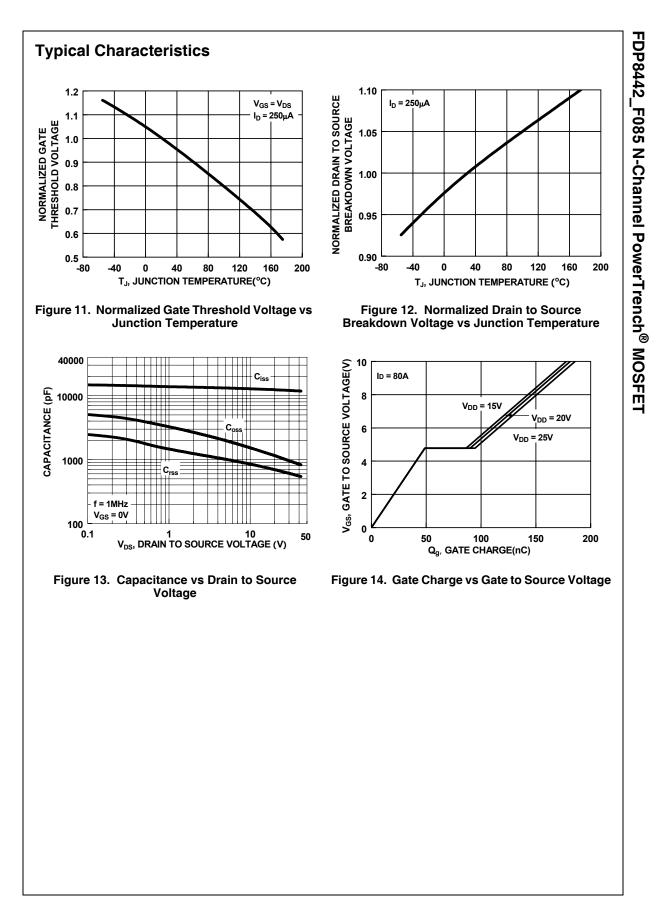
Notes:

Reverse Recovery Charge

**1:** Starting  $T_J = 25^{\circ}C$ , L = 0.35mH,  $I_{AS} = 64A$ **2:** Pulse width = 100s.







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